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DC-DC Converter (-20V, -1.5A) RTF015P02

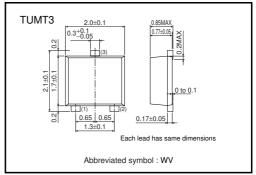
Features

- 1) Low on-resistance. ($80m\Omega$ at 2.5V)
- 2) High power package.
- 3) High speed switching.
- 4) Low voltage drive. (2.5V)

Applications

DC-DC converter

•External dimensions (Unit : mm)



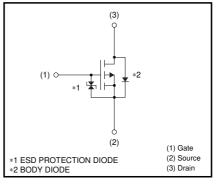
Structure

Silicon P-channel MOS FET

Packaging specifications

	Package	Taping	
Туре	Code	TL	
	Basic ordering unit (pieces)	3000	
RTF015P02		0	

Equivalent circuit





Transistors

●Absolute maximum ratings (Ta=25°C)

		-		
Parameter Drain-source voltage		Symbol	Limits	Unit V
		VDSS	-20	
Gate-source voltage		Vgss	±12	V
Drain current	Continuous	lD	±1.5	А
	Pulsed	DP *1	±6	А
Source current (Body diode)	Continuous	ls *1	-0.6	А
	Pulsed	ISP	-6	А
Total power dissipation		PD *2	0.8	W
Channel temperature		Tch	150	°C
Range of Storage temperature		Tstg	-55 to +150	°C

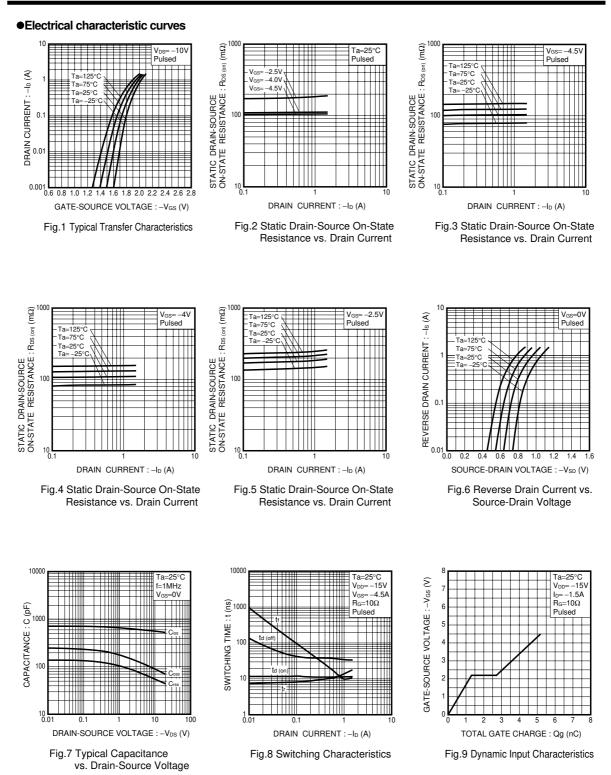
*1 Pw≤10μs, Duty cycle≤1% *2 Mounted on a ceramic board

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	-	-	1 0	μΑ	$V_{GS}=\pm 12V, V_{DS}=0V$	
Drain-source breakdown voltage	$V_{(\text{BR})\text{ DSS}}$	-20	_	-	V	$I_D = -1mA$, $V_{GS} = 0V$	
Zero gate voltage drain current	IDSS	-	-	1–	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate threshold voltage	VGS (th)	-0.7	_	2 .0	٧	V_{DS} = -10V, I_{D} = -1mA	
Static drain-source on-state resistance	R _{DS} (on)	-	100	135	mΩ	$I_D = -1.5A, V_{GS} = -4.5V$	
		-	110	150	mΩ	$I_{D}{=}-1.5A,V_{GS}{=}-4V$	
		-	180	250	mΩ	I_{D} = -1.5A, V_{GS} = -2.5V	
Forward transfer admittance	Y _{fs} *	1.5	_	-	S	$V_{DS} = -10V, I_D = -0.8A$	
Input capacitance	Ciss	-	560	_	pF	$V_{DS} = -10V$	
Output capacitance	Coss	-	90	_	pF	V _{GS} =0V	
Reverse transfer capacitance	Crss	-	55	_	pF	f=1MHz	
Turn-on delay time	td (on) *	-	12	_	ns	$ I_{D} = -0.8A V_{DD} = -15V V_{GS} = -4.5V R_{L} = 9\Omega R_{GS} = 10\Omega $	
Rise time	tr *	-	12	_	ns		
Turn-off delay time	td (off) *	-	38	_	ns		
Fall time	t _f *	-	12	_	ns		
Total gate charge	Qg	-	5.2	_	nC	V _{DD} ≒−15V RL≒10Ω	
Gate-source charge	Qgs	-	1.3	_	nC	$V_{GS} = -4.5V$ R _{GS} = 10 Ω	
Gate-drain charge	Q _{gd}	-	1.4	_	nC	I _D =-1.5A	
Pulsed							
Body diode characteristics (source-drain characteristics)							
Forward voltage	VSD	-	_	1 . 2	V	$I_S = -0.6A$, $V_{GS} = 0V$	

RTF015P02

Transistors



Transistors

Measurement circuits

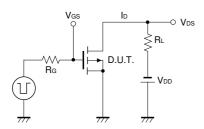


Fig.10 Switching Time Measurement Circuit

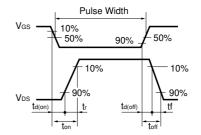


Fig.11 Switching Waveforms

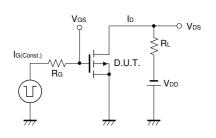


Fig.12 Gate Charge Measurement Circuit

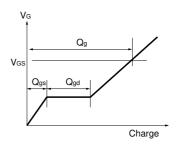


Fig.13 Gate Charge Waveforms

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